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FAIRCHILD

74LCX162244 Low Voltage 16-Bit Buffer/Line Driver with 26 Ω Series Resistors in Outputs

General Description

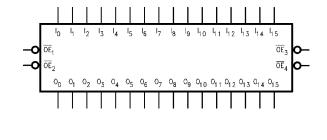
Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- \blacksquare Outputs include equivalent series resistance of 26 Ω to make external termination resistors unnecessary and reduce overshoot and undershoot
- 5.3 ns t_{PD} max (V_{CC} = 3.0V), 20 μA I_{CC} max
- Power down high impedance inputs and outputs
- \blacksquare ±12 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
 - Human body model > 2000V Machine model > 200V

Ordering Code: Order Number Package Number 74LCX162244GX 54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide BGA54A

FAIRCH	JCTOR®		September 2000 Revised May 2005	74LCX162
	age 16-Bi	t Buffer/Lir esistors in		74LCX162244 Low Voltage
3-STATE outputs of and address driver ter/receiver. The d has separate 3-ST/ together for full 16- The LCX162244 is V_{CC} applications wi environment. In addition, the ou series resistors to are designed to sin The LCX162244 is	ntains sixteen non-i lesigned to be emp , clock driver, or bu evice is nibble con ATE control inputs w bit operation. designed for low vo th capability of inter tputs include equiva reduce overshoot a k/source up to 12 m s fabricated with a ve high speed opera-	nverting buffers with loyed as a memory s oriented transmit- trolled. Each nibble hich can be shorted ltage (2.5V or 3.3V) facing to a 5V signal alent 26Ω (nominal) and undershoot and A at V _{CC} = 3.0V. n advanced CMOS ation while maintain-	 Features 5V tolerant inputs and outputs 2.3V-3.6V V_{CC} specifications provided Outputs include equivalent series resistance of 26Ω to make external termination resistors unnecessary and reduce overshoot and undershoot 5.3 ns t_{PD} max (V_{CC} = 3.0V), 20 μA t_{CC} max Power down high impedance inputs and outputs ±12 mA output drive (V_{CC} = 3.0V) Implements patented noise/EMI reduction circuitry Latch-up performance exceeds 500 mA ESD performance: Human body model > 2000V Machine model > 200V Also packaged in plastic Fine-Pitch Ball Grid Array (FBGA) (Preliminary) 	oltage 16-Bit Buffer/Line Driver with 26 Ω
Ordering Co	ode:			26 Ω
Order Number	Package Number		Package Description	ý.
74LCX162244GX (Note 1)	BGA54A (Preliminary)	[TAPE and REEL]	II Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide	Series
74LCX162244MEA (Note 2)	MS48A	48-Lead Small Shrink	COutline Package (SSOP), JEDEC MO-118, 0.300" Wide	
74LCX162244MTD (Note 2)	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide		
	ool 	Specify by appending the su	ffix letter "X" to the ordering code.	Resistors in Outputs
		l ₁ l ₂ l ₃ l ₄ l ₅ l ₆ l ₇	la la ho hi h2 h3 h4 h5 ΘE3 Φ-	outs

Logic Symbol



74LCX162244

Connection Diagrams

i in Acongin	nent for SSC	OP and TSSO	2
OE ₁ -		48 - 0E2	
0 ₀ —	2	47 - 1 ₀	
-0 0 ₁ —	- 3	46 - I ₁	
GND -	4	45 — GND	
0 ₂ -	5	44 - I ₂	
0 ₃ —	6	43 — I ₃	
v _{cc} –	7	42 — V _{CC}	
0 ₄ —	8	4 1 - I ₄	
0 ₅ —	9	40 — I ₅	
GND —	10	39 — GND	
0 ₆ —	11	38 — I ₆	
0 ₇ 0 ₈	12 13	37 — I ₇ 36 — I ₈	
0 ₈ —	14	36 – 1 ₈ 35 – 1 ₉	
GND —	15	34 — GND	
0 ₁₀ —	16	33 — I ₁₀	
0 ₁₁ -	17	32 - I ₁₁	
v _{cc} –	18	31 - V _{CC}	
0 ₁₂ -	19	30 — I ₁₂	
0 ₁₃ —	20	29 — I _{1 3}	
GND —	21	28 — GND	
0 ₁₄ —	22	27 — I ₁₄	
0 ₁₅ -	23	26 - 1 ₁₅	
0E ₄ —	24	25 — OE ₃	
Pin A	ssignment f	or FBGA	
_	1234	56	
<	0000	000	
m	0000		
U	õõõõ		
		a a l	
	0000		
ш	0000		
		õõ	
ш	ŏŏŏŏ		
ш ц	0000		
ц С С С			
ЧЧ С Н С			

Pin Descriptions

Pin Names Description			
<u>OE</u> n	Output Enable Input (Active LOW)		
I ₀ -I ₁₅	Inputs		
O ₀ -O ₁₅	Outputs		
NC	No Connect		

FBGA Pin Assignments

	1	2	3	4	5	6
Α	O ₀	NC	OE ₁	OE ₂	NC	I ₀
В	O ₂	0 ₁	NC	NC	I ₁	l ₂
С	O ₄	O ₃	V _{CC}	V _{CC}	I ₃	I ₄
D	0 ₆	0 ₅	GND	GND	1 ₅	I ₆
Е	O ₈	0 ₇	GND	GND	1 ₇	l ₈
F	O ₁₀	O ₉	GND	GND	l ₉	I ₁₀
G	0 ₁₂	0 ₁₁	V _{CC}	V _{CC}	I ₁₁	I ₁₂
Н	O ₁₄	O ₁₃	NC	NC	I ₁₃	I ₁₄
J	0 ₁₅	NC	\overline{OE}_4	\overline{OE}_3	NC	I ₁₅

Truth Tables

Inp	uts	Outputs	
OE ₁	I ₀ —I ₃	0 ₀ –0 ₃	
L	L	L	
L	н	н	
Н	Х	Z	
Inp	uts	Outputs	
OE ₂	I ₄ –I ₇	0 ₄ -0 ₇	
L	L	L	
L	Н	н	
Н	х	Z	
Inp	Inputs		
OE ₃	I ₈ –I ₁₁	0 ₈ –0 ₁₁	
L	L	L .	
L	L H	н	
_	-	-	
L	H X	- Н	
L	H X	H Z	
L H Inp	H X uts	H Z Outputs	
L H Inp OE ₄	H X uts I ₁₂ -I ₁₅	H Z Outputs O ₁₂ -O ₁₅	
L H Inp OE ₄ L	H X uts I ₁₂ –I ₁₅ L	H Z Outputs O ₁₂ -O ₁₅ L	

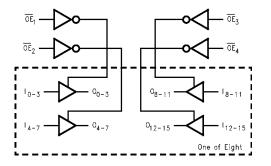
H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial Z = High Impedance

Functional Description

The LCX162244 contains sixteen non-inverting buffers with 3-STATE standard outputs. The device is designed with 26Ω series resistors in the outputs. This design reduces line noise in applications such as memory address drivers, clock drivers and bus transceiver/transmitters. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of the other. The control pins

can be shorted together to obtain full 16-bit operation. The 3-STATE outputs are controlled by an Output Enable (\overline{OE}_n) input for each nibble. When \overline{OE}_n is LOW, the outputs are in 2-state mode. When \overline{OE}_n is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

Logic Diagram



74LCX162244

Absolute Maximum Ratings(Note 3)

Symbol	Parameter	Value	Conditions	Units
V _{CC}	Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	-0.5 to +7.0		V
Vo	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE	V
		–0.5 to V _{CC} + 0.5	Output in HIGH or LOW State (Note 4)	v
I _{IK}	DC Input Diode Current	-50	V _I < GND	mA
I _{OK}	DC Output Diode Current	-50	V _O < GND	mA
		+50	$V_{O} > V_{CC}$	IIIA
lo	DC Output Source/Sink Current	±50		mA
I _{CC}	DC Supply Current per Supply Pin	±100		mA
I _{GND}	DC Ground Current per Ground Pin	±100		mA
T _{STG}	Storage Temperature	-65 to +150		°C

Recommended Operating Conditions (Note 5)

Symbol	Parameter		Min	Max	Units
V _{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	v
VI	Input Voltage		0	5.5	V
Vo	Output Voltage	HIGH or LOW State	0	V _{CC}	V
		3-STATE	0	5.5	v
I _{OH} /I _{OL}	Output Current	V _{CC} = 3.0V - 3.6V		±12	
		$V_{CC} = 2.7V - 3.0V$		±8	mA
		V _{CC} = 2.3V – 2.7V		±4	
T _A	Free-Air Operating Temperature		-40	85	°C
$\Delta t / \Delta V$	Input Edge Rate, $V_{IN} = 0.8V-2.0V$, $V_{CC} = 3.0V$		0	10	ns/V

Note 3: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 4: I_O Absolute Maximum Rating must be observed.

Note 5: Unused control inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	v _{cc}	$T_A = -40$ °C to $+85$ °C		Units
Symbol	Falameter	Conditions	(V)	Min	Max	Units
V _{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		v
VIL	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 - 3.6		0.8	v
V _{OH}	HIGH Level Output Voltage	I _{OH} = -100 μA	2.3 - 3.6	V _{CC} - 0.2		
		$I_{OH} = -4 \text{ mA}$	2.3	1.8		
		$I_{OH} = -4 \text{ mA}$	2.7	2.2		v
		I _{OH} = -6 mA	3.0	2.4		v
		I _{OH} = -8 mA	2.7	2.0		
		I _{OH} = -12 mA	3.0	2.0		
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.3 - 3.6		0.2	
		I _{OL} = 4 mA	2.3		0.6	
		I _{OL} = 4 mA	2.7		0.4	v
		I _{OL} = 6 mA	3.0		0.55	v
		I _{OL} = 8 mA	2.7		0.6	
		I _{OL} = 12 mA	3.0		0.8	
lı –	Input Leakage Current	$0 \le V_I \le 5.5$	2.3 - 3.6		±5.0	μA
I _{OZ}	3-STATE Output Leakage	$0 \le V_O \le 5.5V$	2.3 - 3.6		±5.0	μA
		$V_I = V_{IH} \text{ or } V_{IL}$				

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V _{cc}	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units
Symbol	Faiameter	conditions	(V)	Min	Max	Units
IOFF	Power-Off Leakage Current	$V_{IN} \text{ or } V_{O} = 5.5 V$	0		10	μA
lcc	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 - 3.6		20	μA
ΔI_{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 - 3.6		500	μA

Note 6: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 7: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

AC Electrical Characteristics

			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C, R_L = 500 \Omega$					
Symbol	Parameter	$V_{CC}=3.3V\pm0.3V$		V _{CC} =	V _{CC} = 2.7V C _L = 50 pF		$V_{CC} = 2.5V \pm 0.2V$ $C_L = 30 \text{ pF}$	
	Parameter	C _L =	C _L = 50 pF					
		Min	Max	Min	Max	Min	Max	
t _{PHL}	Propagation Delay	1.0	5.3	1.0	6.0	1.0	6.4	ns
t _{PLH}	Data to Output	1.0	5.3	1.0	6.0	1.0	6.4	
t _{PZL}	Output Enable Time	1.0	6.3	1.0	7.1	1.0	8.2	
t _{PZH}		1.0	6.3	1.0	7.1	1.0	8.2	ns
t _{PLZ}	Output Disable Time	1.0	5.4	1.0	5.7	1.0	6.5	
t _{PHZ}		1.0	5.4	1.0	5.7	1.0	6.5	ns
t _{OSHL}	Output to Output Skew (Note 8)		1.0					20
tOSLH			1.0					ns

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

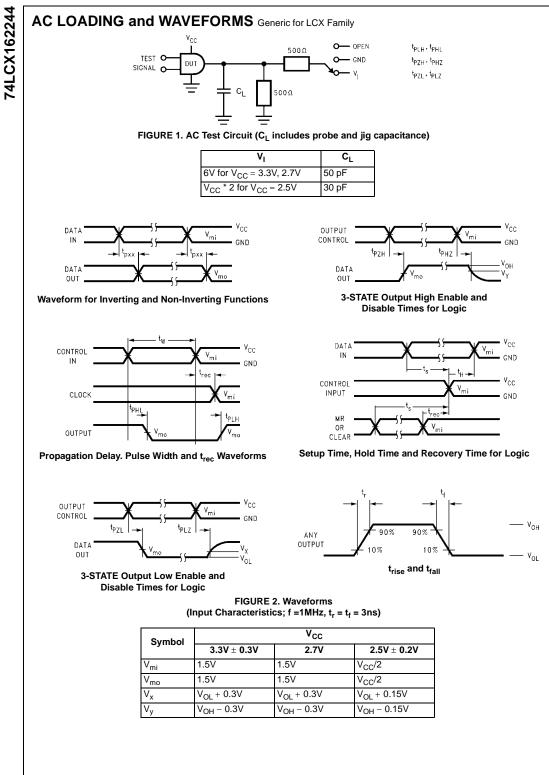
Dynamic Switching Characteristics

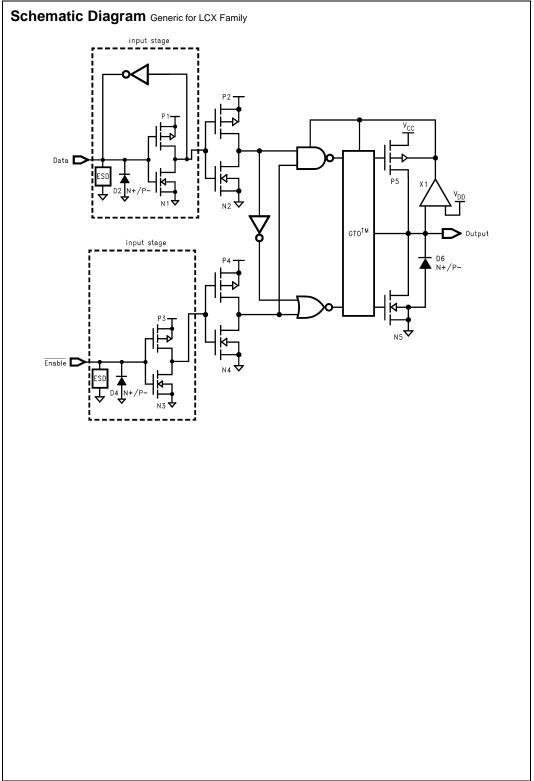
Symbol	Parameter	Conditions	V _{CC} (V)	T _A = 25°C Typical	Units
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	0.35	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	0.25	v
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_{L} = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	-0.35	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	-0.25	v

Capacitance

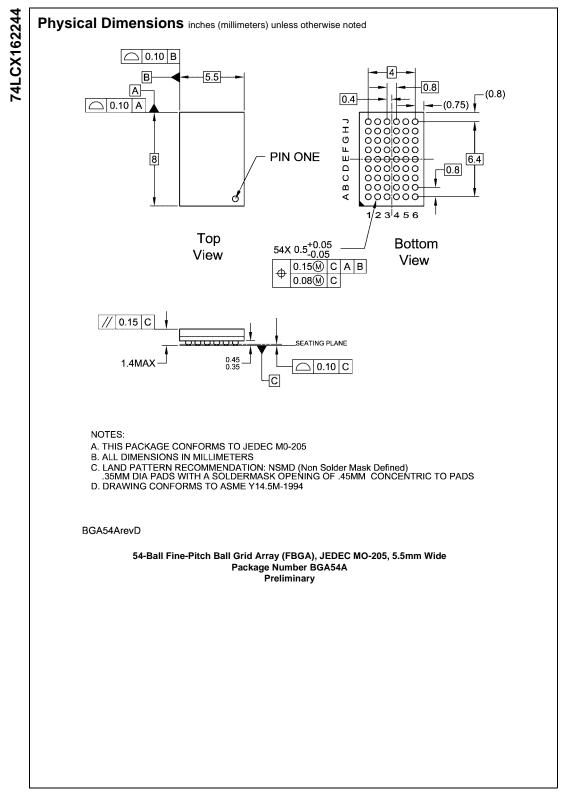
Symbol	Parameter	Typical	Units	
C _{IN}	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} , f = 10 MHz	20	pF

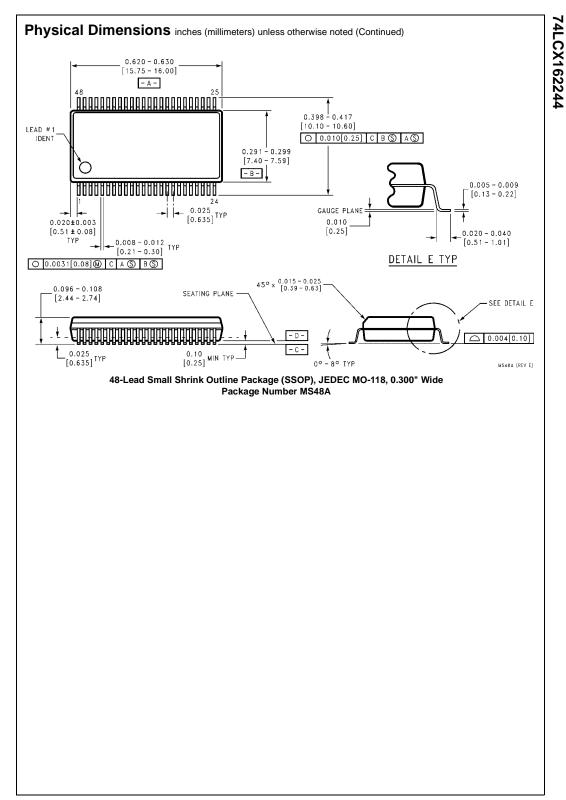
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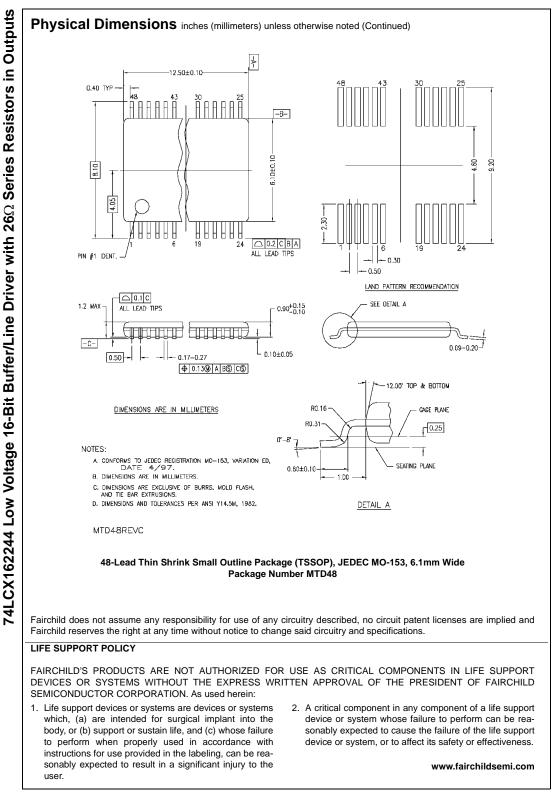




74LCX162244







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